

SHANGHAI SUNRISE ELECTRONICS CO., LTD.

SS32 THRU SS36

SURFACE MOUNT SCHOTTKY **BARRIER RECTIFIER**

TECHNICAL SPECIFICATION

VOLTAGE: 20 TO 60V CURRENT: 3.0A

FEATURES

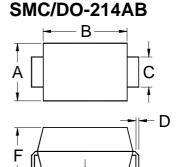
- Ideal for surface mount pick and place application
- Low profile package
- Low power loss, high efficiency
- High current capability, low V_F
- High surge capability
- High temperature soldering guaranteed: 260°C/10sec/at terminal

MECHANICAL DATA

 Terminal: Plated leads solderable per MIL-STD 202E, method 208C

 Case: Molded with UL-94 Class V-O recognized flame retardant epoxy

Polarity: Color band denotes cathode



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	Α	В	С	D	
MAX.	.245(6.22)	.280(7.11)	.124(3.15)	.012(0.305)	
MIN.	.220(5.59)	.260(6.60)	.108(2.75)	.006(0.152)	
	E	F	G	Н	
MAX.	.320(8.13)	.096(2.44)	.008(0.203)	.060(1.52)	
MIN.	.305(7.75)	.084(2.13)	.004(0.102)	.030(0.76)	

Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Single-phase, half-wave, 60Hz, resistive or inductive load rating at 25°C, unless otherwise stated, for capacitive load, derate current by 20%)

RATINGS	SYMBOL	SS32	SS33	SS34	SS35	SS36	UNITS
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	20	30	40	50	60	V
Maximum RMS Voltage	V_{RMS}	14	21	28	35	42	V
Maximum DC Blocking Voltage	V_{DC}	20	30	40	50	60	V
Maximum Average Forward Rectified Current	$I_{F(AV)}$	3.0					Α
(T _L =100°C)							
Peak Forward Surge Current (8.3ms single	I _{FSM}	100					А
half sine-wave superimposed on rated load)							
Maximum Instantaneous Forward Voltage	V_{F}		0.5		0.7		V
(at rated forward current)		0.5					V
Maximum DC Reverse Current T _a =25°C	1	0.5					mΑ
(at rated DC blocking voltage) T _a =100°C	I _R	20.0					mA
Typical Junction Capacitance (Note 1)	C_J	300					pF
Typical Thermal Resistance (Note 2)	R _θ (ja)	15					°C/W
Storage and Operation Junction Temperature	T_{STG},T_{J}	-65 to +150					°C
Mata							

- 1.Measured at 1.0 MHz and applied voltage of 4.0V_{dc}
- 2. Thermal resistance from junction to terminal mounted on 5×5mm copper pad area